Substitute for form 1449A/PTO

INFORMATION DISCLOSURE STATEMENT BY APPLICANT

(use as many sheets as necessary)

Sheet

	Complete if Known
Application Number	10/773,950
Filing Date	February 6, 2004
First Named Inventor	Takuo Tamura
Art Unit	2818
Examiner Name	Dao H. Nguyen
Attorney Docket Number	16869S-029220US

		Document Number		1.		
Examiner Initials*	Cite No. ¹	Number Kind Code ² (if known)	Publication Date MM-DD-YYYY	Name of Patentee or Applicant of Cited Document	Pages, Columns, Lines, Where Relevant Passages or Relevant Figures Appear	
dly	1 .	US-6,190,949	02-20-2001·	Noguchi et al.	1	
	2	US-6,150,203	11-21-2000	Yamazaki et al.		
	3	US-5,981,974	11-09-1999	Makita	•	
	4	US-5,904,550	05-18-1999	Yamaguchi		
dhe	5	US-5,882,960	03-16-1999	Zhang et al.	1	
		·				

FOREIGN PATENT DOCUMENTS								
Examiner Cite	Foreign Patent Document				Name of Patentee or	Pages, Columns, Lines, Where Relevant		
Initials*	No. ¹	Country Code ³	Number ⁴	Kind Code ⁸ (<i> known</i>)	Publication Date MM-DD-YYYY	Applicant of Cited Document	Passages or Relevant Figures Appear	T⁵
dhen	6	JP	11-195608	Α	07-21-1999	Hitachi Ltd.		Ø
dhir	7	JP	10-41234	Α	02-13-1998	Sony Corp.		⊠
dly	-8	EP	0598394	A2	05-25-1994	Tokyo Electron Ltd.		
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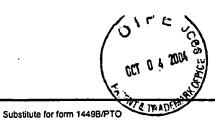
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NON PATENT LITERATURE DOCUMENTS						
Examiner Initials *	Cite No.1	Include name of the author (in CAPITAL LETTERS), title of the article (when appropriate), title of the item (book, magazine, journal, serial, symposium, catalog, etc.), date, page(s), volume-issue number(s), publisher, city and/or country where published.	T2			
dhu	9	KURIYAMA et al. "Lateral Grain Growth of Poly-Si Films with a Specific Orientation by an Excimer Laser Annealing Method," Japanese Journal of Applied Physics December 1993, volume 32, pages 6190-6195 (1993).				
dha	10	KURIYAMA "Excimer laser crystallization of silicon films for AMLCDs," Proceedings of Second International Workshop on Active Matrix Liquid Crystal Displays (AMLCDs '95) September 25-26 1995 Bethlehem, PA (1995).				
dlu	11	KURIYAMA et al. "Lateral Grain Growth in the Excimer Laser Crystallization of Poly-Si," Proceedings of the Materials Research Society Symposium November 1993, volume 321, pages 657-662 (1993).				

Examiner Signature	Moas	Date Considered	01/14/2205

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